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Hyperfast Rectifier, 30 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I _{F(AV)} 30 A							
V _R	600 V						
V _F at I _F at 125 °C	1.15 V						
t _{rr} (typ.)	25						
I _{FSM}	330						
T _J max.	175 °C						
Package	TO-247AD 3L						
Circuit configuration	Single						

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- · Optimized for high speed operation
- FREE • 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: TO-247AD 3L Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage	V _{RRM}		600	V					
Average rectified forward current	I _{F(AV)}	T _C = 123 °C, D = 0.50	30						
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave, both anodes, (1) and (3) connected	330	А					
Repetitive peak forward current	I _{FRM}	T _C = 123 °C, D = 0.50, f = 20 kHz	60						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-		
Forward voltage	V _F	I _F = 30 A	-	1.3	1.6	V	
		I _F = 30 A, T _J = 125 °C	-	1.15	-		
Poverse leekage ourrent	I _R	$V_{R} = V_{R}$ rated	-	-	20		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V _R = 200 V	-	36	-	pF	
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH	

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100$	$I_F = 1.0 \text{ A}, \text{ d}_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$			-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	41	-	ns	
		T _J = 125 °C		-	58	-		
Peak recovery current	I _{RRM}	T _J = 25 °C	I _F = 20 A, dI _F /dt = 1000 A/μs, V _R = 400 V	-	19	-	A	
Feak recovery current		T _J = 125 °C		-	32	-		
	0	T _J = 25 °C		-	419	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1176	-		
		T _J = 25 °C		-	46	-		
Reverse recovery time	t _{rr}	T _J = 125 °C		-	65	-	ns	
Deals receiver a surrent		T _J = 25 °C	I _F = 30 A, dI _F /dt = 1000 A/μs, V _B = 400 V	-	21	-	А	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	36	-	A	
	Q _{rr}	T _J = 25 °C		-	550	-		
Reverse recovery charge		T _J = 125 °C]	-	1560	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.1	°C/W		
Weight			-	5.5	-	g		
			-	0.2	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style: TO-247AD 3L	A5PH3006L					

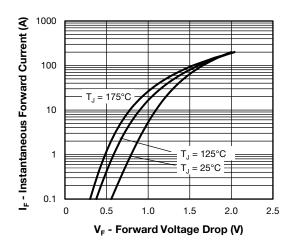


Fig. 1 - Forward Voltage Drop Characteristics

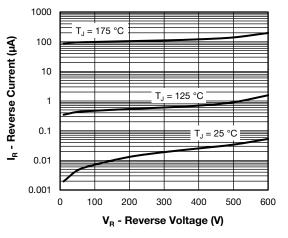


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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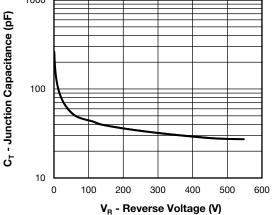


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

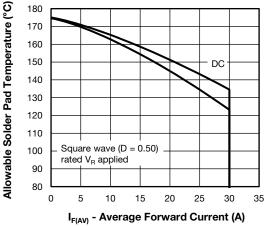
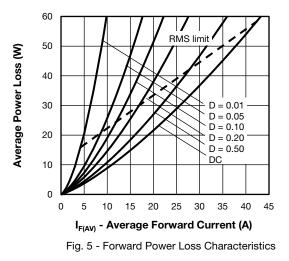


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current



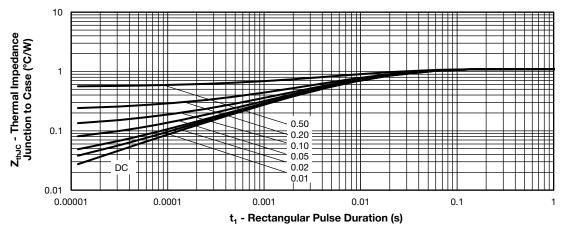


Fig. 6 - Transient Thermal Impedance, Junction to Case

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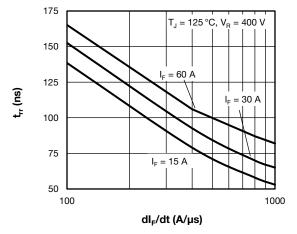


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

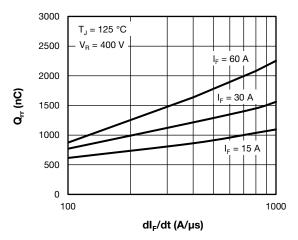


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

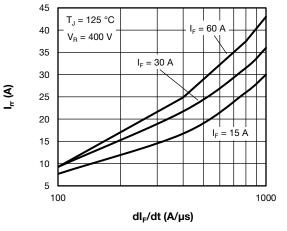


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

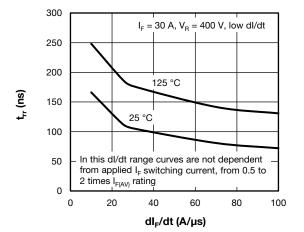
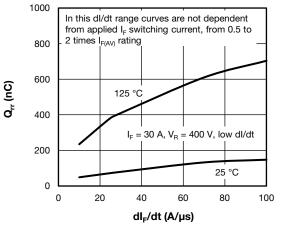


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt





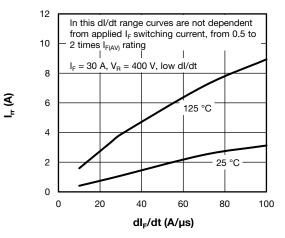


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

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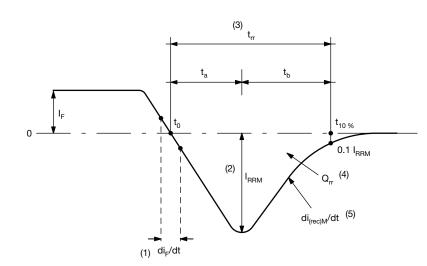


Fig. 13 - Reverse Recovery Waveform and Definitions

- Notes
- ⁽¹⁾ di_F/dt rate of change of current through zero crossing

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- ⁽²⁾ I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ $\, Q_{rr}^{}$ area under curve defined by t_0 and $t_{10\ \%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

⁽⁵⁾ $di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code	VS-	Α	5	Ρ	н	30	06	L	-N3
	1	2	3	4	5	6	7	8	9
	1 - 2 - 3 - 4 -	A = 5 = Pac	single o Fred ge kage:	hiconduc liode, 2 neratior	anodes 15				
	5 -			ist recov					
	6 -			ng (30 =	,				
	7 -		0	ng (06 =	,				
	8 -		0	= long l	`)-247AL)		
	9 -			ntal digit gen-free		complia	ant, and	totally I	ead (Pb

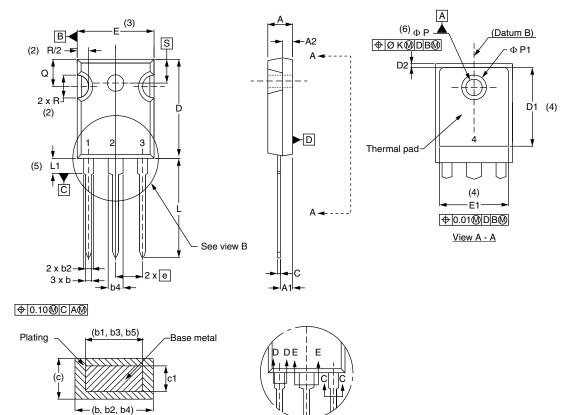
ORDERING INFORMATION (Example)								
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION								
VS-A5PH3006L-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95626						
Part marking information	www.vishay.com/doc?95007					



TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.209 A 4.65 5.31 0.183 0.087 0.102 A1 2.21 2.59 1.50 2.49 0.059 0.098 A2 b 0.99 1.40 0.039 0.055 b1 0.99 1.35 0.039 0.053 b2 1.65 2.39 0.065 0.094 b3 1.65 2.34 0.065 0.092 b4 2.59 3.43 0.102 0.135 b5 2.59 3.38 0.102 0.133 с 0.38 0.89 0.015 0.035 c1 0.38 0.84 0.015 0.033 D 19.71 20.70 0.776 0.815 3 D1 13.08 -0.515 4

(4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	٥.254 v		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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